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** CONTINUING DATA *****

None - BC

** FOREIGN APPLICATIONS *****

JAPAN 2002-279880 09/25/2002

✓ BC

IF REQUIRED, FOREIGN FILING LICENSE GRANTED

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Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 5	TOTAL CLAIMS 32	INDEPENDENT CLAIMS 16
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged	Examiner's Signature BC	Initials		

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TITLE

Methods for producing silicon nitride films and silicon oxynitride films by thermal chemical vapor deposition

FILING FEE	FEES: Authority has been given in Paper	<input type="checkbox"/> All Fees
		<input type="checkbox"/> 1.16 Fees (Filing)
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